





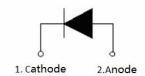
S4D40120H 1200V SIC POWER SCHOTTKY RECTIFIER



Description

S4D40120H is a SiC Schottky rectifier packaged in TO-247AC(TO-247-2) case. The device is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S4D40120H is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- · Reverse polarity protection

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

Maximum Ratings

| Characteristics | Symbol | Condition | Max. | Units |
|---------------------------------------|----------------------|---|------|------------------|
| Peak Repetitive Reverse Voltage | V_{RRM} | - | | |
| Working Peak Reverse Voltage | V_{RWM} | | 1200 | V |
| DC Blocking Voltage | V_R | | | |
| Average Rectified Forward Current | I _{F (AV)1} | T _C =25°C | 128 | А |
| | I _{F (AV)2} | T _C =155°C | 41 | А |
| Peak One Cycle Non-Repetitive Surge | I _{FSM1} | 10ms, Half Sine pulse, T _C =25°C | 340 | Α |
| Current | I _{FSM2} | 10ms, Half Sine pulse, T _C =110°C | 245 | Α |
| | I _{FRM1} | 10ms, Half Sine pulse , T _C =25°C | 161 | Α |
| Repetitive Peak Forward Surge Current | I _{FRM2} | 10ms, Half Sine pulse , T _C =110°C | 91 | Α |
| | P _{tot1} | T _C =25°C | 667 | W |
| Power Dissipation | P _{tot2} | T _C =110°C | 289 | W |
| I²t Value | ∫i²t1 | 10ms, Tc=25℃ | 305 | A ² s |
| i i-t value | ∫i²t2 | 10ms, Tc=25℃ | 300 | A ² s |

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Electrical Characteristics:

| Characteristics | Symbol | Condition | Тур. | Max. | Units |
|---------------------------|-----------------|--|------|------|-------|
| Forward Voltage Drop* | V _{F1} | @ 40A, Pulse, T _J = 25 °C | 1.5 | 1.8 | V |
| | V _{F2} | @ 40A, Pulse, T _J = 175 °C | 2.2 | 3.0 | V |
| Reverse Current* | I _{R1} | @V _R = rated V _R , T _J = 25 °C | 2 | 30 | uA |
| | I _{R2} | @V _R = rated V _R , T _J = 175 °C | 10 | 300 | uA |
| Junction Capacitance | Ст | VR=0V, f=1MHz, Tj=25℃, | 3227 | - | pF |
| Reverse Recovery Charge | Qc | VR = 800 V, T _J =25°C | 167 | - | nC |
| Capacitance Stored Energy | Ec | V _R = 800 V, T _J =25°C | 36 | - | μJ |

^{*} Pulse width < 300 µs, duty cycle < 2%

Thermal-Mechanical Specifications:

| Characteristics | Symbol | Condition | Specification | Units |
|---|----------------|-----------------------|---------------|-------|
| Junction Temperature | ΤJ | - | -55 to +175 | °C |
| Storage Temperature | T_{stg} | - | -55 to +175 | °C |
| Typical Thermal Resistance Junction to Case | $R_{	heta JC}$ | DC operation, Tj=25°C | 0.225 | °C/W |

Electrostatic Discharge (ESD) Classifications:

| Parameter | Symbol | Value |
|---------------------|--------|---------------------|
| Human Body Model | НВМ | Class 3B (≥ 8000 V) |
| Charge Device Model | CDM | Class C3 (≥ 1000 V) |

Ordering Information

| Device | Package | Shipping |
|-----------|--------------------|--------------|
| S4D40120H | TO-247AC(TO-247-2) | 25pcs / tube |

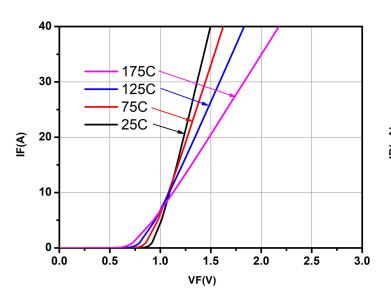
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Ratings and Characteristics Curves



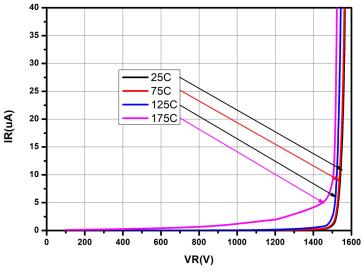
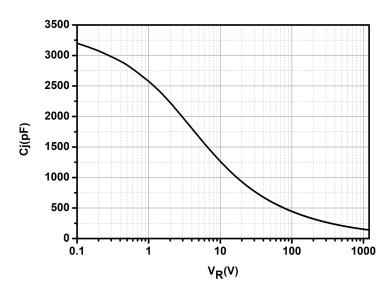
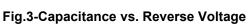


Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics





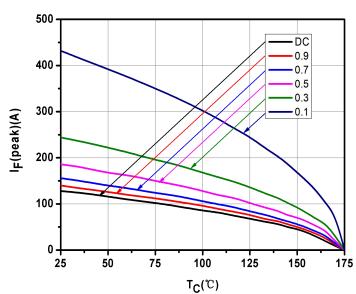


Fig.4-Current Derating

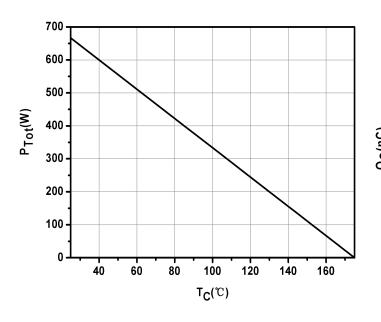
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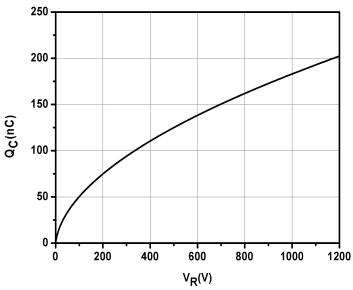


Fig.5-Power Derating

Fig.6-Total Capacitance Charge vs. Reverse Voltage

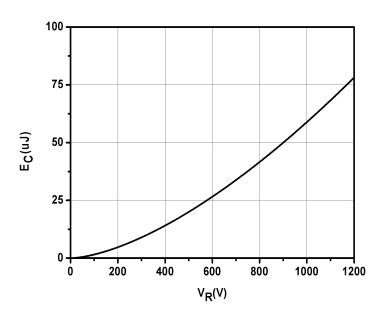


Fig.7-Capacitance Stored Energy

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Marking Diagram



Where XXXXX is YYWWL

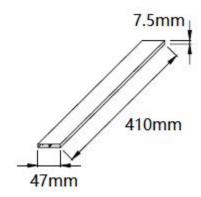
S4D = Device Type H = Package type 40 = Forward Current (40A) 120 = Reverse Voltage (1200V)

120 = Reverse Voltage
SSG = SSG
YY = Year
WW = Week
L = Lot Number

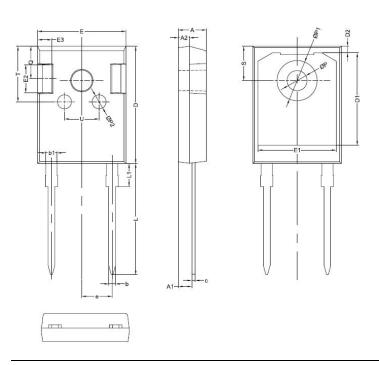
Cautions: Molding resin

Epoxy resin UL:94V-0

Tube Specification(TO-247AC(TO-247-2)



Mechanical Dimensions TO-247AC(TO-247-2)



| A 4.80 5.00 5. A1 2.20 2.41 2. A2 1.90 2.00 2. b 1.10 1.20 1. b1 1.80 2.00 2. c 0.50 0.60 0. D 20.30 21.00 21 D1 16.58 D2 1.17 E 15.60 15.80 16 E1 14.02 E2 5.00 E3 2.50 e 5.44 | AX. 20 61 10 |
|--|---------------------|
| A1 2.20 2.41 2. A2 1.90 2.00 2. b 1.10 1.20 1. b1 1.80 2.00 2. c 0.50 0.60 0. D 20.30 21.00 21 D1 16.58 D2 1.17 E 15.60 15.80 16 E1 14.02 E2 5.00 E3 2.50 E3 e 5.44 | .61 .10 |
| A2 1.90 2.00 2. b 1.10 1.20 1. b1 1.80 2.00 2. c 0.50 0.60 0. D 20.30 21.00 21 D1 16.58 1.17 E 15.60 15.80 16 E1 14.02 E2 5.00 E3 2.50 E e 5.44 5.44 | 10 |
| b 1.10 1.20 1. b1 1.80 2.00 2. c 0.50 0.60 0. D 20.30 21.00 21 D1 16.58 1.17 E E 15.60 15.80 16 E1 14.02 E2 5.00 E3 2.50 E e 5.44 5.44 | 10 |
| b1 1.80 2.00 2. c 0.50 0.60 0. D 20.30 21.00 21 D1 16.58 D2 1.17 E 15.60 15.80 16 E1 14.02 E2 5.00 E3 2.50 e 5.44 | ~- |
| b1 1.80 2.00 2. c 0.50 0.60 0. D 20.30 21.00 21 D1 16.58 D2 1.17 E 15.60 15.80 16 E1 14.02 E2 5.00 E3 2.50 e 5.44 | .35 |
| D 20.30 21.00 21 D1 16.58 16.58 16.58 16 D2 1.17 16.58 16 <td>.20</td> | .20 |
| D1 16.58 D2 1.17 E 15.60 15.80 16 E1 14.02 E2 5.00 E3 2.50 e 5.44 | 75 |
| E1 14.02 E2 5.00 E3 2.50 e 5.44 | .20 |
| E1 14.02 E2 5.00 E3 2.50 e 5.44 | |
| E1 14.02 E2 5.00 E3 2.50 e 5.44 | |
| E1 14.02 E2 5.00 E3 2.50 e 5.44 | .00 |
| E2 5.00 E3 2.50 e 5.44 | |
| E3 2.50 e 5.44 | |
| e 5.44 | |
| 1 10 10 10 00 00 | |
| L 19.42 19.92 20 | .42 |
| L1 4.13 | |
| P 3.50 3.60 3. | 70 |
| | 40 |
| P2 2.50 | |
| Q 5.80 | |
| | 25 |
| T 10.00 | |
| U 6.20 | |

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